TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SH14FE

SCHMITT INVERTER

Features

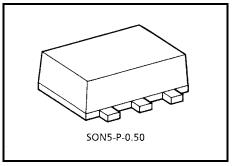
• Super high speed operation :tpD = 5.5 ns (typ.)

$$@V_{CC} = 5 \text{ V}$$

• Low power dissipation : I_{CC} = 2 μ A (Max.) @ Ta = 25°C

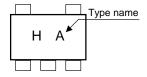
• 5.5V tolerant input.

• Wide operation voltage range : V_{CC} (opr) = 2~5.5 V

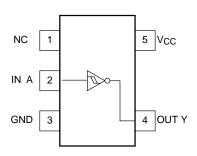


Weight: 0.003 g (typ.)

Marking



Pin Assignment (top view)

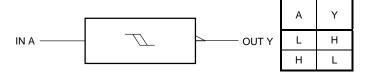


Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5~7	V
DC input voltage	V _{IN}	-0.5~7	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	I _{OK}	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	P _D	150	mW
Storage temperature	T _{stg}	-65~150	°C

Logic Diagram

Truth Table



Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	Vcc	2~5.5	٧
Input voltage	V _{IN}	0~5.5	V
Output voltage	V _{OUT}	0~ V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~100 (V_{CC} = 3.3 V ± 0.3 V)	ns/V
	ui/uv	0~20 (V_{CC} = 5 $V \pm 0.5 V$)	115/ V

Electrical Characteristics

DC Characteristics

Characteristics Symbol		Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
				V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
				3.0			2.20		2.20	٧
Positive Threshold Voltage	V_{P}	_		4.5			3.15		3.15	
							3.85		3.85	
		_		3.0	0.90		_	0.90		
Negative Threshold Voltage	V_N			4.5	1.35	_	_	1.35	_	V
				5.5	1.65	_	_	1.65	_	
				3.0	0.30		1.20	0.30	1.20	
Hysteresis Voltage	V_{H}	_		4.5	0.40		1.40	0.40	1.40	V
				5.5	0.50		1.60	0.50	1.60	
		$V_{IN} = V_{IL}$	I _{OH} = -50 μA	2.0	1.9	2.0	_	1.9	_	
				3.0	2.9	3.0	_	2.9	_	
High-level output voltage VOI	V _{OH}			4.5	4.4	4.5	_	4.4	_	V
			I _{OH} = -4 mA	3.0	2.58	_	_	2.48	_	
			I _{OH} = -8 mA	4.5	3.94		_	3.80	_	
Low-level output voltage V _{OL}			$I_{OL} = 50 \mu A$ $I_{OL} = 4 \text{ mA}$	2.0	_	0	0.1	_	0.1	V
				3.0	_	0	0.1	_	0.1	
	V_{OL}	$V_{IN} = V_{IH} \\$		4.5	_	0	0.1	_	0.1	
				3.0	_	_	0.36	_	0.44	
			I _{OL} = 8 mA	4.5	_	_	0.36	_	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V	V _{IN} = 5.5 V or GND		_	_	±0.1	_	±1.0	μΑ
Quiescent supply current	Icc	$V_{IN} = V_{CC}$	or GND	5.5	_	_	2.0	_	20.0	μА



AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
			V _{CC} (V)	C _{L (} pF)	Min	Тур.	Max	Min	Max	Offic
Propagation delay time	[†] PLH [†] PHL	3.3 ± 0.3 5.0 ± 0.5	22402	15	_	8.3	12.8	1.0	15.0	
			50	_	10.8	16.3	1.0	18.5	ns	
			F 0 0 F	15	_	5.5	8.6	1.0	10.0	1115
			50	_	7.0	10.6	1.0	12.0		
Input capacitance	CIN				_	4	10	_	10	pF
Power dissipation capacitance	C _{PD}		(Note)		_	14	_		_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

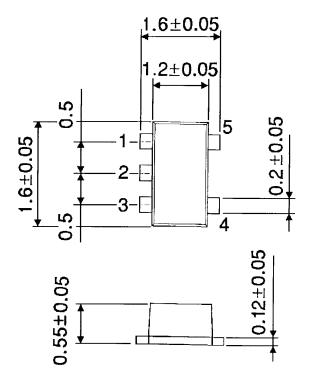
Average operating current can be obtained by the equation.

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$



Package Dimensions

SON5-P-0.50 Unit: mm



Weight: 0.003 g (typ.)

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